

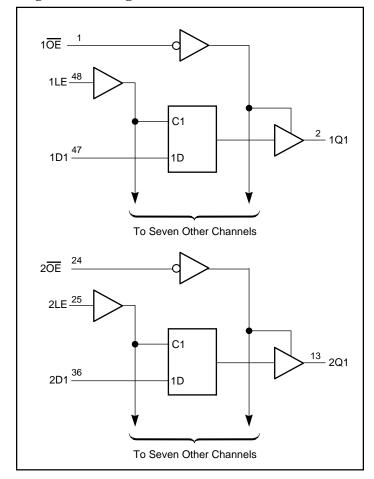
PI74ALVCH16373

16-Bit Transparent D-Type Latch with 3-STATE Outputs

Product Features

- PI74ALVCH16373 is designed for low voltage operation
- $V_{CC} = 2.3V \text{ to } 3.6V$
- Hysteresis on all inputs
- Typical V_{OLP} (Output Ground Bounce) < 0.8V at $V_{CC} = 3.3V$, $T_A = 25^{\circ}C$
- Typical V_{OHV} (Output V_{OH} Undershoot) < 2.0 V at $V_{CC} = 3.3 \text{V}$, $T_A = 25 ^{\circ}\text{C}$
- Bus Hold retains last active bus state during 3-STATE, eliminating the need for external pullup resistors
- Industrial operation at -40°C to +85°C
- · Packages available:
 - 48-pin 240 mil wide plastic TSSOP (A)
 - 48-pin 300 mil wide plastic SSOP (V)

Logic Block Diagram



Product Description

Pericom Semiconductor's PI74ALVCH series of logic circuits are produced in the Company's advanced 0.5 micron CMOS technology, achieving industry leading speed.

This 16-bit transparent D-type latch is designed for 2.3V to 3.6V V_{CC} operation.

The PI74ALVCH16373 is particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers. This device can be used as two 8-bit latches or one 16-bit latch. When the Latch Enable (LE) input is HIGH, the Q outputs follow the (D) inputs. When LE is taken LOW, the Q outputs are latched at the levels set up at the D inputs.

A buffered Output Enable (OE) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state in which the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components. \overline{OE} does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high impedance state.

To ensure the high impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

PS8093B 10/09/00



Product Pin Description

Pin Name	Description
$\overline{\text{OE}}$	Output Enable Input (Active LOW)
LE	Latch Enable (Active HIGH)
Dx	Data Inputs
Qx	3-State Outputs
GND	Ground
$V_{\rm CC}$	Power

Truth Table(1)

	Outputs		
OE	LE	D	Q
L	Н	Н	Н
L	Н	L	L
L	L	X	Q ₀
Н	X	X	Z

Notes:

1. H = High Signal Level

L = Low Signal Level

X = Irrelevant

Z = High Impedance

Product Pin Configuration

Toduct Fill Coll	iigu			
1 0 E	√ 1	$\overline{}$	48	1LE
1Q1	2		47	1D1
1Q2	3		46	1D2
GND			45	GND
1Q3	Д ⁻ П 5		44	1D3
1Q4			43	1D4
VCC	7 7		42	VCC
1Q5	٦ ′ □ 8		41	1D5
1Q6		48-Pin	40	1D6
GND	10 10		39	GND
1Q7	10 11	V,A	38	1D7
1Q8	日 ' ' [] 12		37	1D8
2Q1	'2 13		36	2D1
2Q2	14		35	2D2
GND	15 15		34	GND
2Q3	16		33	2D3
2Q4	17		32	2D4
VCC	18		31	VCC
2Q5	19		30	2D5
2Q6	20		29	2D6
GND	21		28	GND
2Q7	22		27	2D7
2Q8	23		26	2D8
2 <u>0E</u>	24		25	2LE
20L	<u> </u>			ZLL



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature	-65° C to $+150^{\circ}$ C
Ambient Temperature with Power Applied	40°C to +85°C
Input Voltage Range, VIN	
Output Voltage Range, VOUT	
DC Input Voltage	
DC Output Current	100 mA
Power Dissipation	1.0W

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

DC Electrical Characteristics (Over the Operating Range, $T_A = -40$ °C to +85°C, $V_{CC} = 3.3V \pm 10\%$)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
V _{CC}	Supply Voltage		2.3		3.6	
VIH ⁽³⁾	I JUOUN I	$V_{CC} = 2.3V \text{ to } 2.7V$	1.7			
VIH.	Input HIGH Voltage	$V_{CC} = 2.7V \text{ to } 3.6V$	2.0			
V _{II} . ⁽³⁾	Innut I OW Valtage	$V_{CC} = 2.3V \text{ to } 2.7V$			0.7	
VIII.	Input LOW Voltage	$V_{CC} = 2.7V \text{ to } 3.6V$			0.8	
V _{IN} ⁽³⁾	Input Voltage		0		V _{CC}	
V _{OUT} ⁽³⁾	Output Voltage		0		V_{CC}	
		I_{OH} = -100 μ A, V_{CC} = Min. to Max.	V _{CC} -0.2			
		$V_{IH} = 1.7V$, $I_{OH} = -6mA$, $V_{CC} = 2.3V$	2.0			V
V _{OH}	Output HIGH	$V_{IH} = 1.7V$, $I_{OH} = -12mA$, $V_{CC} = 2.3V$	1.7			V
	Voltage	$V_{IH} = 2.0V$, $I_{OH} = -12mA$, $V_{CC} = 2.7V$	2.2			
		$V_{IH} = 2.0V, I_{OH} = -12mA, V_{CC} = 3.0V$	2.4			
		$V_{IH} = 2.0V$, $I_{OH} = -24mA$, $V_{CC} = 3.0V$	2.0			
		I_{OL} = 100 μ A, V_{IL} = Min. to Max.			0.2	
	Output	$V_{IL} = 0.7V$, $I_{OL} = 6mA$, $V_{CC} = 2.3V$			0.4	
V _{OL}	LOW Voltage	$V_{IL} = 0.7V$, $I_{OL} = 12mA$, $V_{CC} = 2.3V$			0.7	
	voluge	$V_{IL} = 0.8V$, $I_{OL} = 12mA$, $V_{CC} = 2.7V$			0.4	
		$V_{IL} = 0.8V$, $I_{OL} = 24mA$, $V_{CC} = 3.0V$			0.55	
	Output	$V_{CC} = 2.3V$			-12	
I _{OH} ⁽³⁾	HIGH Current	$V_{CC} = 2.7V$			-12	
	Current	$V_{CC} = 3.0V$			-24	
	Output	V _{CC} = 2.3V			12	mA
I _{OL} ⁽³⁾	LOW Current	V _{CC} = 2.7V			12	
	Curcii	$V_{CC} = 3.0V$			24	



DC Electrical Characteristics-Continued (Over the Operating Range, $T_A = -40$ °C to +85°C, $V_{CC} = 3.3V \pm 10\%$)

Parameters	Description	Test Conditions ⁽¹⁾	Min.	Typ. ⁽²⁾	Max.	Units
I _{IN}	Input Current	$V_{IN} = V_{CC}$ or GND, $V_{CC} = 3.6V$			±5	
		$V_{IN} = 0.7V, V_{CC} = 2.3V$	45			
	Input	$V_{IN} = 1.7V, V_{CC} = 2.3V$	-45			
I _{IN} (HOLD)	Hold Current	$V_{IN} = 0.8V, V_{CC} = 3.0V$	75			
	Current	$V_{IN} = 2.0V, V_{CC} = 3.0V$	-75			
		$V_{IN} = 0$ to 3.6V, $V_{CC} = 3.6V$			±500	μΑ
I _{OZ}	Output Current (3-STATE Outputs)	$V_{OUT} = V_{CC}$ or GND, $V_{CC} = 3.6V$			±10	
I _{CC}	Supply Current	$V_{CC} = 3.6V$, $I_{OUT} = 0\mu A$, $V_{IN} = GND$ or V_{CC}			40	
ΔI_{CC}	Supply Current per Input @ TTL HIGH	$V_{CC} = 3.0 \text{V}$ to 3.6V One Input at $V_{CC} - 0.6 \text{V}$ Other Inputs at V_{CC} or GND			750	
C	Control Inputs	V V CND V 22V		3		
C_{I}	Data Inputs	$V_{IN} = V_{CC}$ or GND, $V_{CC} = 3.3V$		6		pF
Co	Outputs	$V_O = V_{CC}$ or GND, $V_{CC} = 3.3V$		7		

Notes:

1. For conditions shown as Max. or Min., use appropriate value specified under Electrical Characteristics for the applicable device type.

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- 2. Typical values are at $V_{CC} = 3.3V$, $+25^{\circ}C$ ambient and maximum loading.
- 3. Unused Control Inputs must be held HIGH or LOW to prevent them from floating.

Timing Requirements over Operating Range

Parameters	Description	$V_{\rm CC} = 2.5 \text{V} \pm 0.2 \text{V}$		$V_{\rm CC} = 2.7V$		$V_{CC} = 3.3V \pm 0.3V$		Units
Parameters		Min.	Max.	Min.	Max.	Min.	Max.	Units
t_{W}	Pulse Duration LE HIGH or LOW	3.3		3.3		3.3		
tsu	Setup Time Data Before LE↓	1.0		1.0		1.1		ns
t _H	Hold Time Data After LE↓	1.5		1.7		1.4		
$\Delta t/\Delta v^{(1)}$	Input Transition Rise or Fall	0	10	0	10	0	10	ns/V

Note:

1. Unused control inputs must be held HIGH or LOW to prevent them from floating.



Switching Characteristics over Operating Range⁽¹⁾

Parameters	E (INDITE)	To (OUTDUT)	$V_{CC} = 2.5V \pm 0.2V$		$V_{CC} = 2.7V$		$V_{CC} = 3.3V \pm 0.3V$		T Imita
	From (INPUT)	To (OUTPUT)	Min. ⁽²⁾	Max.	Min.	Max.	Min. ⁽²⁾	Max.	Units
tpD	D		1.0	4.5		4.3	1.1	3.6	
t _{PD}	LE	0	1.0	5.9		4.6	1.0	3.9	****
$t_{\rm EN}$	ŌE	Q	1.0	6.0		5.7	1.0	4.7	ns
t _{DIS}	ŌĒ		1.9	5.1		4.5	1.4	4.1	

Notes:

- 1. See test circuit and waveforms.
- 2. Minimum limits are guaranteed but not tested on Propagation Delays.

Operating Characteristics, $T_A = 25^{\circ}C$

Parameter		Test Conditions	$V_{CC} = 2.5V \pm 0.2V$	$V_{CC} = 3.3V \pm 0.3V$	Units
		Test Conditions	Ту	Cints	
C _{PD} Power Dissipation	Outputs Enabled	$C_{L} = 50 \text{pF}, f = 10 \text{ MHz}$	19	22	pF
Capacitance	Outputs Disabled	CL = 30pr, r = 10 mnz	4	5	pr.

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